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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/041,720	01/07/2002	Joseph J. Dlugokecki	20646-719	4175
7590 03/04/2004			EXAMINER	
KIEUN JENNY SUNG			CHAMBLISS, ALONZO	
GARY, CARY, WARE & FREIDENRICH 1755 Embarcadero Road Palo Alto, CA 94303			ART UNIT	PAPER NUMBER
			2827	

DATE MAILED: 03/04/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

		1/14/				
	Application No.	Applicant(s)				
	10/041,720	DLUGOKECKI ET AL.				
Office Action Summary	Examiner	Art Unit				
	Alonzo Chambliss	2827				
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply lift NO period for reply is specified above, the maximum statutory period.  - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).		nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 11 L	December 2003					
·_ ·	s action is non-final.					
3) Since this application is in condition for allowa		secution as to the merits is				
	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
<ul> <li>4)  Claim(s) 1-22 is/are pending in the application 4a) Of the above claim(s) is/are withdra 5)  Claim(s) is/are allowed.</li> <li>6)  Claim(s) 1-22 is/are rejected.</li> <li>7)  Claim(s) is/are objected to.</li> <li>8)  Claim(s) are subject to restriction and/or are subject.</li> </ul>	awn from consideration.					
Application Papers						
9) ☐ The specification is objected to by the Examination 10) ☒ The drawing(s) filed on <u>07 January 2002</u> is/are Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Examination 11.	e: a) accepted or b) objected or b) objection is required if the drawing(s) is objection is required if the drawing(s) is objected or b).	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureat * See the attached detailed Office action for a list	nts have been received.  Its have been received in Applicationity documents have been received in the contract of the contract	on No ed in this National Stage				
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da	•				
2) Motice of Draftsperson's Patent Drawing Review (P10-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date		atent Application (PTO-152)				

#### **DETAILED ACTION**

1. Amendment A filed on 12/11/03 has been fully considered and made of record in Paper No. 6. Furthermore, the previous non-final rejection has been withdrawn and the new non-final rejections are set forth below.

### Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 1-4, 8, 9, 11, 13, and 21 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Dlugokecki (U.S, 5,318,926).

With respect to Claim 1, Dlugokecki teaches deconstructing an integrated circuit package for exposing a wire bond pad and a lead frame located therein in col. 6 lines 24-68 and col. 7 lines 1-15. Attaching a die 62 to exposed wire bond pads of a lead frame 65 so that the die 62 is electrically connected to the lead frame 65. The die 62 and wire bond pads are encapsulated by an encapsulant 82 and reshaping of the upper surface of the encapsulant 82 where at least a portion of the encapsulant reshaping is performed by a lapping process (i.e. process of removing a material) (see col. 7 lines 16-68; Figs. 4-8).

Art Unit: 2827

With respect to Claims 2 and 3, Dlugokecki teaches wherein lapping is performed by ablative lapping process (i.e. a process to remove by cutting) and mechanically (see col. 6 lines 47-66).

With respect to Claim 4, Dlugokecki teaches wherein encapsulating the die 62 and the wire bond pads results in the encapsulant 82 having a convex or concave an upper surface, and reshaping the encapsulant 82 results in the encapsulant 82 having a planar an upper surface (see col. 7 lines 51-65; Figs. 5 and 8).

With respect to Claims 8, 9, 11, 13, and 21, Dlugokecki teaches wherein lapping is performed using a planar abrasive surface (i.e. mechanical grinding utilizing a wheel to initial the motion of the grind), chemical etching, or plasma etching (see col. 6 lines 47-68).

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was

Art Unit: 2827

not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

5. Claims 5 and 6 are rejected under 35 U.S.C. 103(a) as being unpatentable over Dlugokecki (U.S. 5,318,926) as applied to claim 1 above, and further in view of Minamio et al. (U.S. 6,680,220).

With respect to Claims 5 and 6, Dlugokecki fails to disclose marking the upper surface of an encapsulant that is sufficiently flat to permit labeling by mechanical marking techniques to simulate a production transfer molded encapsulated IC package. However, Minamio discloses marking the upper surface of an encapsulant 6 that is sufficiently flat to permit labeling by mechanical marking 12-14 techniques to simulate a production transfer molded encapsulated IC package (see abstract and col. 8 lines 23-46; Figs. 8A, 8B, 9A, 9B, 10, and 11). Therefore, it would have been obvious to incorporate a marking on the upper surface of the encapsulant of Dlugokecki, since the marking would label the type of semiconductor device manufactured after the transfer molding process as taught by Minamio.

6. Claims 7 and 15-17 are rejected under 35 U.S.C. 103(a) as being unpatentable over Dlugokecki (U.S. 5,318,926) as applied to claim 1 above, and further in view of Capote et al. (U.S. 6,566,234).

With respect to Claims 7 and 16, Dlugokecki both fail to disclose wherein lapping is performed using laser ablation. However, Capote discloses wherein lapping (i.e. process of removing a material) is performed using laser ablation (see col. 8 lines 55-

Art Unit: 2827

60). Therefore, it would have been obvious to substitute a laser ablation process for the mechanical process taught by Dlugokecki, since the laser ablation would facilitate the removal of the encapsulant material from the surface of the semiconductor device as taught by Capote.

With respect to Claims 15 and 17, one skilled in the art would readily recognize utilizing the combination of mechanical and electromagnetic ablation or the combination of electromagnetic and chemical ablation process with the process of Dlugokecki, since the combination would effectively improve the time needed to remove the desired amount of encapsulant from a semiconductor device.

7. Claim 10 is rejected under 35 U.S.C. 103(a) as being unpatentable over Dlugokecki (U.S. 5,318,926) as applied to claim 1 above, and further in view of Tani et al. (U.S. 6,080,602).

With respect to Claim 10, Dlugokecki fails to disclose wherein lapping is performed to permit more than one package to be lapped at the same time. However, Tani discloses lapping is performed to permit more than one package to be lapped at the same time (see Fig. 3D). Thus, Dlugokecki and Tani have substantially the same environment of lapping an encapsulant material. Therefore, it would have been obvious to incorporate lapping of more than one package, since the lapping process would decrease the lapping time and reduce the cost of making semiconductor devices as taught by Tani.

Art Unit: 2827

8. Claims 12, 14, 18-20, and 22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Dlugokecki (U.S. 5,318,926) as applied to claim 1 above, and further in view of Wensink (4,384,917).

With respect to Claims 12, 18-20, and 22, Dlugokecki does not explicitly discloses wherein lapping is performed using a gas that has an ultra-fine particulate using a high pressure and a pulsating liquid jet containing a particulate material under high pressure. However, Wensink discloses wherein lapping is performed using a gas that has an ultra-fine particulate using a high pressure and a liquid jet having some level of pulsating (i.e. based on the flow of liquid through the jet pump) that contains a particulate material under high pressure (see col. 2 lines 42-51). Dlugokecki and Wensink both have substantially the same environment of utilizing a lapping process to reduce the thickness of an encapsulant material on a semiconductor device. Therefore, it would have been obvious to one skilled in the art at the time of the invention to incorporate the jet lapping process into the process of Dlugokecki, since the jet would facilitate rapid and safe of the reduction in the thickness of an encapsulant material on a semiconductor device as taught by Wensink.

With respect to Claim 14, one skilled in the art would readily recognize utilizing the combination of a mechanical and chemical ablation process taught by Dlugokecki, since the combination would effectively improve the time needed to remove the desired amount of encapsulant from a semiconductor device.

The prior art made of record and not relied upon is cited primarily to show the process of the instant invention.

## Conclusion

9. Any inquiry concerning the communication or earlier communications from the examiner should be directed to Alonzo Chambliss whose telephone number is (703) 306-9143. The fax phone number for this Group is (703) 308-7722 or 7724.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-7956

AC/February 8, 2004

Alonzo Chambliss
Patent Examiner
Art Unit 2827

Page 7